```
AN
       1993:451037 CAPLUS
 DN
       119:51037
  ED
       Entered STN: 07 Aug 1993
       Epoxy resin compositions for semiconductor
 TI
       sealants
  IN
       Kondo, Akihiro
  PA
       Sumitomo Bakelite Co., Ltd., Japan
  SO
       Jpn. Kokai Tokkyo Koho, 4 pp.
       CODEN: JKXXAF
 DT
       Patent
       Japanese
 LΑ
  IC
       ICM H01L023-29
       ICS H01L023-31; C08K003-22; C08K005-09; C08L061-10; C08L063-00
       38-3 (Plastics Fabrication and Uses)
       Section cross-reference(s): 76
  FAN.CNT 1
       PATENT NO.
                        KIND
                              DATE
                                             APPLICATION NO.
                                                               DATE
 PΤ
       JP 05003269
                         A 2.
                              19930108
                                             JP 1991-152945
                                                               19910625
 PRAI JP 1991-152945
                              19910625
       The title compns. with good heat and fire resistance contain 0.01-10
 AB
 parts
       reducing agents vs. 100 parts mixts. comprising epoxy
       resins, phenol novolak resin hardeners,
      hardening accelerators, Sb203, halogenated epoxy resins
       , inorg. fillers, and other additives. Thus fused SiO2 70, epoxy
       resin (200 epoxy equiv) 18, phenol novolak
       resin (104 OH value) 9, diazabicycloundecene 0.5, Sb203 3, halogenated
       epoxy resin (270 epoxy equiv) 2, carnauba wax
       2, carbon black 0.3, and oxalic acid 8 parts were melt kneaded, crushed,
       molded at 175.degree., and post-cured at 175.degree. for 8 h to obtain
       test pieces showing resistance 0.7 .OMEGA. initially and <1 .OMEGA. after
       400 h at 200.degree..
       epoxy resin compn semiconductor
 ST
       sealant; heat resistant epoxy potting compn; fireproof
       epoxy resin compn sealant; reducing agent
       epoxy resin sealant
IT
       Epoxy resins, uses
       RL: USES (Uses)
          (blends, with phenol novolak resins and halogenated
          epoxy resins, contg. reducing agents, for
          sealing semiconductors)
 IT
       Reducing agents
          (epoxy resin compns. contg., for sealing
         semiconductors, heat-resistant)
 IT
      Heat-resistant materials
          (epoxy resin compns., contg. novolak
         phenolic resin curing agents and reducing agents, for sealing
          semiconductors)
 İT
      Electronic device packaging
          (epoxy resin compns., contg. novolak
         phenolic resin curing agents and reducing agents, for
          semiconductors, heat-resistant)
 IT
      Epoxy resins, compounds
      RL: USES (Uses)
          (halogenated, blends, with epoxy resins and
         novolak phenolic resins, contg. reducing agents, for
         sealing semiconductors)
 IT
      Phenolic resins, uses
```

VON

RL: MOA (Modifier or additive use); USES (Uses) (novolak, crosslinking agents, for epoxy resin compns., for sealing semiconductors)

IT 39350-32-8, Diazabicycloundecene

RL: USES (Uses)

(curing accelerators, epoxy resin compns. contg.,
for sealing semiconductors)

IT 1309-64-4, Diantimony trioxide, uses

RL: USES (Uses)

(epoxy resin compns. contg., for sealing
semiconductors)

IT 60676-86-0, Fused silica

RL: USES (Uses)

(fillers, epoxy resin compns. contg., for

sealing semiconductors)

IT 50-81-7, (Ascorbic acid) miscellaneous 144-62-7, Oxalic acid,

miscellaneous

RL: MSC (Miscellaneous)

(reducing agents) epoxy resin compns. contg., for

sealing semiconductors)

DERWENT-ACC-NO:

1993-050471

DERWENT-WEEK:

199306

COPYRIGHT 1999 DERWENT INFORMATION LTD

TITLE:

Resin compsn. for IC(s) with

improved storage life at

higher temp. - contg. reducing agent,

epoxy! resin,

phenol! novolak resin curing agent

curing accelerator,

antimony oxide, halogenated epoxy!

resin, inorganic

filler, etc.

PATENT-ASSIGNEE: SUMITOMO BAKELITE CO[SUMB]

PRIORITY-DATA: 1991JP-0152945 (June 25, 1991)

PATENT-FAMILY:

PUB-NO

PUB-DATE

LANGUAGE

PAGES

MAIN-IPC

JP 05003269 A

January 8, 1993

N/A

004

H01L 023/29

APPLICATION-DATA:

PUB-NO

APPL-DESCRIPTOR

APPL-NO

APPL-DATE

JP 05003269A

N/A

1991JP-0152945

June 25, 1991

INT-CL (IPC): C08K003/22, C08K005/09, C08L061/10,

C08L063/00 ,

H01L023/29 , H01L023/31

ABSTRACTED-PUB-NO: JP 05003269A

BASIC-ABSTRACT:

Compsn. contains 0.1-10 wt. parts reduction agent added to a 100 wt. parts of resin compsn. made of an epoxy resin, a phenol novolak resin curing agent, a curing accelerator, an antimony oxide, a halogenated epoxy

resin, an inorganic filler and other additives.

ADVANTAGE - Improved fire resistance, mouldability and storage life at higher temp..

In an example, a compsn. was prepd. by blending (wt. parts): (70) fused silica,

(18) epoxy resin, (9) phenol novolak resin curing agent,

di-aza-bicyclo-undecene, (3) antimony trioxide, halogenated epoxy resin, (2)

carnauba wax, (0.3) carbon black and (8) oxalic acid, mulled at 95-100 deg.C.

in a co-kneader, cooled, pulverised and tablettted to sealing resin compsn. for

semiconductor. The compsn. was cured for 2 minutes at 175 deq.C. and post

cured for 8 hours at 175 deq.C.. A test of the moulded compsn. held at 200

deq.C. and inspected every 50 hours showed that resistance was not changed for

400 hours compared with the initial 0.7 ohm

CHOSEN-DRAWING: Dwg.0/0

TITLE-TERMS: RESIN COMPOSITION IC IMPROVE STORAGE LIFE HIGH TEMPERATURE CONTAIN

REDUCE AGENT POLYEPOXIDE RESIN POLYPHENOL

NOVOLAK RESIN CURE AGENT

CURE ACCELERATE ANTIMONY OXIDE HALOGENATED

POLYEPOXIDE RESIN

INORGANIC FILL

ADDL-INDEXING-TERMS:

INTEGRATED CIRCUIT

DERWENT-CLASS: A21 A85 L03 U11

CPI-CODES: A05-A01E2; A05-C01B; A08-D; A08-D01; A08-F02; A08-F04A; A08-R01;

A09-A01; A12-E07C; L04-C20A;

EPI-CODES: U11-A07;

UNLINKED-DERWENT-REGISTRY-NUMBERS: 1152U; 1527U; 1669U; 1694U ; 5085U ; 5087U

PATENT ABSTRACTS OF JAPAN

(11)Publication number:

05-003269

(43) Date of publication of application: 08.01.1993

(51)Int.CI.

H01L 23/29 H01L 23/31 C08K 3/22 C08K 5/09 C08L 61/10 C08L 63/00

(21) Application number: 03-152945

(71)Applicant:

SUMITOMO BAKELITE CO LTD

(22) Date of filing:

25.06.1991

(72)Inventor:

KONDO AKIHIRO

(54) RESIN COMPOSITE

(57) Abstract:

PURPOSE: To obtain a semiconductor sealing composite excellent for storage at high-temperature by consisting mainly of an epoxy resin, a phenol novolac resin curing agent, a curing promoter, antimony oxide, a halide epoxy resin, fused silica, and oxalic acid or arcorbic acid.

CONSTITUTION: A semiconductor sealing resin composite consists mainly of an epoxy resin, a phenol novolac resin curing agent, a curing promoter, antimony oxide, a halide epoxy resin, and an inorganic filler. For example, fused silica 70 parts epoxy. resin (epoxy equivalent 200) 18 parts, phenol novolac resin curing agent (hydroxyl equivalent 104) 9 parts, DBU 0.5 parts, antimony trioxide 3 parts, halide epoxy resin (epoxy equivalent 270) 3 parts, carnauba wax 2 parts, carbon black 0.3 parts, and oxalic acid 8 parts as the reducing agent are mixed sufficiently at a normal temperature. Further, the mixture is kneaded by a cokneader at 95-100°C. It is crushed after cooling into tablets as molding materials.

LEGAL STATUS

[Date of request for examination]

08.01.1998

[Date of sending the examiner's decision of rejection]

03.08.1999

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

[Date of registration]

[Number of appeal against examiner's decision of rejection]

Date of requesting appeal against examiner's decision of

rejection]

[Date of extinction of right]

Copyright (C); 1998,2003 Japan Patent Office

* NOTICES *

Japan Patent Office is not responsible for any damages caused by the use of this translation.

- 1. This document has been translated by computer. So the translation may not reflect the original precisely.
- 2.**** shows the word which can not be translated.
- 3.In the drawings, any words are not translated.

DETAILED DESCRIPTION

[Detailed Description of the Invention] [0001]

[Industrial Application] This invention relates to the resin constituent for the semi-conductor closures excellent in the elevated-temperature storage property and burning resistance suitable for the closures of high integration IC. [0002]

[Description of the Prior Art] Although the closure of the electronic parts, such as an integrated circuit, is conventionally carried out with thermosetting resin, the operating environment reaches far and wide from an elevated temperature and the dryness to [from the low temperature] the humid condition. The above-mentioned electronic parts used for an automobile etc. in it are exposed to the severest conditions, and the fall of the dependability under highly humid poses especially a problem recently. That is, a large number [the example of an actual proof that the reed wire which connects this chip and lead is disconnected] although above-mentioned electronic parts consist of a chip, a lead, etc.

[0003] What is depended on AL line on a chip and the corrosion for a bonding area of a reed wire (Au line) other than deformation of the reed wire by impregnation of the resin at the time of shaping as a cause of an open circuit can be considered. As a report of exfoliation of Au and AL interface, there is BELL ** (L. G.Feinstein) (1980) etc. partly, there are many views of what is depended on the impurity contained in a resin constituent, especially halogen ion, and when exposed to an elevated temperature, it has appeared notably.

[0004] Generally the halogenation epoxy resin contributed to the burning-resistance property called a flame retarder to the resin constituent for the semi-conductor closures as a thing containing a halogen is added. Usually, it is used combining a halogenation epoxy resin and antimony oxide in many cases as a flame retarder. Although it had corresponded by increasing the addition of a flame retarder to heat-resistant improvement, it was only difficult for the inconvenient phenomenon of reducing not only the problem of industrial regulation but an elevated-temperature storage property to produce the increment in an addition, and to obtain the resin constituent with which both properties are compatible.

[0005]

[Problem(s) to be Solved by the Invention] In order that this invention may solve troubles, such as an open circuit by the corrosion of the wire-bonding section under the conventional high temperature service, it was made as a result of various examination, and the place made into the purpose offers the resin constituent for the semi-conductor closures excellent in the elevated-temperature storage property, without degrading burning resistance and a moldability.

[0006]

[Means for Solving the Problem] That is, this invention is a resin constituent for the semi-conductor closures characterized by adding the reducing agent of 0.01 - 10 weight section to the resin constituent 100 weight section which consists of an epoxy resin, a phenol novolak resin curing agent, a hardening accelerator, antimony oxide, a halogenation epoxy resin, an inorganic filler, and other additives.

[0007] As for the epoxy resin used for this invention, bisphenol mold epoxy, phenol novolak mold epoxy, heterocycle mold epoxy, these denaturation objects, etc. are mentioned, and these may be independent or may be used together. A halogenation epoxy resin has bisphenol mold epoxy, novolak mold epoxy, etc. A phenol novolak resin curing agent has a phenol novolak, cresol novolaks, these denaturation objects, etc.

[0008] To one hydroxyl group of a curing agent, the compounding ratio of an epoxy resin and a phenol novolak resin curing agent needs to adjust combination so that it may become within the limits of 0.5-2 about the number of epoxy groups of an epoxy resin. If less than 0.5 and 2 are exceeded, moisture resistance, shaping workability, and the electrical property of a hardened material will worsen. Preferably, the combination which the number of epoxy groups of an epoxy resin makes within the limits of 1.1-1.3 to one hydroxyl group of a curing agent is suitable. Absorptivity goes up, the thermal shock at the time of solder immersion increases, and the thing exceeding less than 1.1 and 1.3 has the inclination for solder-proof stress nature to worsen.

[0009] a hardening accelerator can use widely what is generally used for the charge of closure material that what is necessary is just what promotes the reaction of an epoxy group and a phenolic hydroxyl group, for example, has diazabicycloundecen (DBU), triphenyl phosphine, dimethyl benzylamine, 2-methylimidazole, etc., and is independent -- or it is used together and used. Fused silica powder, spherical silica powder, and crystal silica powder, secondary condensation silica powder, porosity silica powder, etc. are mentioned to an inorganic filler, and especially fused silica powder is desirable.

[0010] Although the resin constituent for the semi-conductor closures of this invention uses an epoxy resin, a phenol novolak resin curing agent, a hardening accelerator, antimony oxide, a halogenation epoxy resin, and an inorganic filler as a principal component, other than this, various additives, such as low stress additives, such as release agents, such as coloring agents, such as a silane coupling agent, carbon black, and red ocher, a natural wax, and a synthetic wax, and silicone oil, and rubber, are blended suitably, and it does not interfere.

[0011] Although the hydride, a metal salt, an organic acid, etc. are generally mentioned as a reducing agent, the most of the hydride is a liquid, the addition approach is difficult, and

since dependability falls, a metal salt is not desirable. Although an organic acid acts on an oxidizer and a reducing agent by the case, as a reducing agent used for this invention, an organic acid with very low oxidation capacity is desirable. For example, there are a formic acid, oxalic acid, arcorbic-acid, etc., and oxalic acid especially with few carbon numbers is desirable. The halogenation epoxy resin used as a flame retarder and antimony oxide can demonstrate the synergistic effect of flameproofing greatly with the combination. However, the halogenation epoxy resin has the problem which is said that a halogen tends to separate at the time of an elevated temperature faced with the cause of corrosion. [0012] However, this problem can be solved in combination with a reducing agent. The addition of a reducing agent has the desirable range of 0.01 - 10 weight section to the resin constituent 100 weight section which consists of an epoxy resin, a phenol novolak resin curing agent, a hardening accelerator, antimony oxide, a halogenation epoxy resin, an inorganic filler, and other additives. If it is under the 0.01 weight section, the engine performance cannot fully be demonstrated. If 10 weight sections are exceeded, the hardenability at the time of closure shaping will get worse. As the addition approach of a reducing agent, after carrying out heating fusion of a halogenation epoxy resin and the little phenol novolak resin curing agent beforehand, add a reducing agent, it is made to cool quickly, this cooling object is ground, and the method of mixing with a residual component is also.

[0013]

[Example] Hereafter, an example explains this invention concretely. The section of the blending ratio of coal expresses the weight section.

The example Dfused-silica 70 section, the epoxy resin (weight per epoxy equivalent 200) 18 section, The phenol novolak resin curing agent (hydroxyl equivalent 104) 9 section, DBU The oxalic acid 8 section was fully mixed in ordinary temperature as the 0.5 sections, the antimony-trioxide 3 section, a halogenation epoxy resin (weight per epoxy equivalent 270), the carnauba wax 2 section, the carbon black 0.3 section, and a reducing agent, and it kneaded by the ko kneader at further 95-100 degrees C, and ground after cooling, and as a molding material, this was tablet-ized and the resin constituent for the semi-conductor closures was obtained. Shaping hardening of the obtained ingredient was carried out on the die temperature of 175 degrees C, and the conditions for setting-time 2 minutes, and postcure of the obtained mold goods was carried out in 175 degrees C and 8 hours. These mold goods were left in the 200-degree C thermostat, and were taken out every 50 hours, and resistance between the lead pins of mold goods was investigated. An evaluation result is shown in Table 1.

[0014] Example 2 reducing agent was made into arcorbic-acid, and also it was presupposed that it is the same as that of an example 1. An evaluation result is shown in Table 1.

[0015] By the blending ratio of coal shown in one to example of comparison 3 table 1, the resin constituent for the semi-conductor closures was obtained by the same approach as an example 1. The evaluation result is shown in Table 1.

[0016] Rate of change of the resistance at the time of applying an electrical potential difference between each lead of evaluation approach * elevated-temperature resistance

rate-of-change mold goods (chip size 36mm2, 2.0mm of package thickness, wire-bonding **). Less than 1-ohm time amount is made into O to the initial resistance of 0.7 ohms. [0017]

[Table 1]

表 1

		実 施 例		比 較 例			
		1	2	l	2	3	
エポキシ樹脂 フェノールノボラック樹脂 DBU 三酸化アンチモン ハロゲン化エポキシ樹脂 溶融シリカ カルナバワックス カーボンブラック		18 9 0.5 3 2 70 2 1.3					
還元	シュウ酸	8			0.005	15	
剤	アルコルビン酸		8			.*	
硬化	硬化性		0	0	0	成形不可	
	50時間(200℃)	0	0	0	0		
高	100	0	0	0	0		
温	150	Ö	0	0	0		
抵	200	0	0	0	0	-	
抗	250	0	0				
変	300	0	0				
動	350	0	0				
率	400	0	0				
	450						

[0018]

[Effect of the Invention] According to this invention, it is the resin constituent excellent in the elevated-temperature storage property which maintained balance extremely the resin constituent for the semi-conductor closures excellent in burning resistance and a moldability is not only obtained, but, and is industrial very reliable.

[Translation done.]

* NOTICES *

Japan Patent Office is not responsible for any damages caused by the use of this translation.

- 1. This document has been translated by computer. So the translation may not reflect the original precisely.
- 2.**** shows the word which can not be translated.
- 3.In the drawings, any words are not translated.

CLAIMS

[Claim(s)]

[Claim 1] The resin constituent for the semi-conductor closures characterized by adding the reducing agent of 0.01 - 10 weight section to the resin constituent 100 weight section which consists of an epoxy resin, a phenol novolak resin curing agent, a hardening accelerator, antimony oxide, a halogenation epoxy resin, an inorganic filler, and other additives.

[Translation done.]

(19)日本国特許庁(JP)

(12) 公開特許公報(A)

(11)特許出願公開番号

特開平5-3269

(43)公開日 平成5年(1993)1月8日

(51)Int.Cl. ⁵		識別記号	庁内整理番号	FΙ			技術表示簡所
HOIL	23/29						
	23/31						
C 0 8 K	3/22	NKV	7167—4 J				
	5/09	NKZ	7167—4 J				
			8617-4M	H01L	23/ 30	R	
				審査請求 未請求	請求項の数 1 (全	全 4 頁)	最終頁に続く
(21)出願番号	}	特願平3-152945		(71)出願人	000002141		
					住友ベークライト	株式会社	
(22)出願日		平成3年(1991)6	月25日		東京都千代田区内	李町1丁	目2番2号
				(72)発明者	近藤 晃弘		
					東京都千代田区内	李町1丁	目2番2号 住
					友ペークライト棋	試会社内	

(54)【発明の名称】 樹脂組成物

(57)【要約】

【構成】 エポキシ樹脂、フェノールノボラック樹脂硬化剤、硬化促進剤、三酸化アンチモン、ハロゲン化エポキシ樹脂、溶融シリカおよびシュウ酸またはアルコルビン酸を主成分とする半導体封止用樹脂組成物。

【効果】 本樹脂組成物で封止された電子部品は、高温保管特性に優れており、高温条件下でチップとリードをつなぐリードワイヤーが断線する問題がない。更に本樹脂組成物は耐燃性および成形性にも優れておりバランスの優れた材料である。

【特許請求の範囲】

【請求項1】 エポキシ樹脂、フェノールノボラック樹 脂硬化剤、硬化促進剤、酸化アンチモン、ハロゲン化エ ポキシ樹脂、無機充填材およびその他の添加物からなる 樹脂組成物100重量部に対し0.01~10重量部の 還元剤を添加することを特徴とする半導体封止用樹脂組 成物。

【発明の詳細な説明】

[0001]

【産業上の利用分野】本発明は高集積度 I Cの封止用に 10 性物等がある。 適する高温保管特性および耐燃性に優れた半導体封止用 樹脂組成物に関するものである。

[0002]

【従来の技術】従来より集積回路等の電子部品は熱硬化 性樹脂で封止されているが、使用環境は低温から高温、 乾燥状態から多湿状態までの広範囲にわたっている。そ の中で自動車等に使用される上述の電子部品は最も苛酷 な条件にさらされており、最近高湿下における信頼性の 低下が、特に問題となっている。即ち、上述の電子部品 はチップとリード等よりなるが、このチップとリードを 20 ス性が悪くなる傾向がある。 つなぐリードワイヤが断線するとの実証例も多数ある。 【0003】断線の原因として、成形時の樹脂の注入に よるリードワイヤの変形の他に、チップ上のAL線とリ ードワイヤ (Au線) のボンディング部分の腐食による もの等が考えられる。AuとAL界面の剥離の報文とし て、BELL研(L. G. Feinstein) (19 80) 等いくつかあり、樹脂組成物中に含まれる不純 物、特にハロゲンイオンによるものとの見方が多く、高 温にさらされた場合それが顕著に現れている。

【0004】半導体封止用樹脂組成物にはハロゲンを含 30 むものとして難燃剤と呼ばれる耐燃性特性に寄与するハ ロゲン化エポキシ樹脂が、一般に添加されている。通常 難燃剤としてハロゲン化エポキシ樹脂と酸化アンチモン とを組み合わせて使用することが多い。耐熱性の向上に 対しては難燃剤の添加量を増加することで対応してきた が、単に添加量の増加は工業的規制の問題ばかりでなく 高温保管特性を低下させる不都合な現象が生じ、両特性 が両立可能な樹脂組成物を得ることは困難であった。

[0005]

件下におけるワイヤーボンディング部の腐食による断線 等の問題点を解決するため、種々の検討の結果なされた もので、その目的とするところは耐燃性および成形性を 劣化させることなく、高温保管特性に優れた半導体封止 用樹脂組成物を提供するものである。

[0006]

【問題を解決するための手段】即ち、本発明はエポキシ 樹脂、フェノールノボラック樹脂硬化剤、硬化促進剤、 酸化アンチモン、ハロゲン化エポキシ樹脂、無機充填材 およびその他の添加物からなる樹脂組成物100重量部 50 ともなるという問題を有している。

に対し0.01~10重量部の還元剤を添加することを 特徴とする半導体封止用樹脂組成物である。

【0007】本発明に用いるエポキシ樹脂はビスフェノ ール型エポキシ、フェノールノボラック型エポキシ、複 素環型エポキシおよびこれらの変性物等が挙げられ、こ れらは単独でも併用してもよい。ハロゲン化エポキシ樹 脂はビスフェノール型エポキシ、ノボラック型エポキシ 等がある。フェノールノボラック樹脂硬化剤はフェノー ルノボラック、クレゾールノボラックおよびこれらの変

【0008】エポキシ樹脂とフェノールノボラック樹脂 硬化剤の配合比は、硬化剤の水酸基数1に対し、エポキ シ樹脂のエポキシ基数を0.5~2の範囲内になるように 配合を調整する必要がある。0.5未満または2を越える と耐湿性、成形作業性および硬化物の電気特性が悪くな る。好ましくは、硬化剤の水酸基数1に対し、エポキシ 樹脂のエポキシ基数が1.1~1.3の範囲内とする配合が 好適である。1.1未満または1.3を越えたものは、吸水 性が上がり半田浸漬時の熱衝撃が増加し、耐半田ストレ

【0009】硬化促進剤はエポキシ基とフェノール性水 酸基との反応を促進するものであればよく、一般に封止 用材料に使用されているものを広く使用することがで き、例えばジアザビシクロウンデセン (DBU)、トリ フェニルホスフィン、ジメチルベンジルアミンや2メチ ルイミダゾール等があり、単独もしくは併用して用いら れる。無機充填材には溶融シリカ粉末、球状シリカ粉 末、結晶シリカ粉末、2次凝集シリカ粉末、多孔質シリ カ粉末等が挙げられ、特に溶融シリカ粉末が好ましい。 【0010】本発明の半導体封止用樹脂組成物はエポキ シ樹脂、フェノールノボラック樹脂硬化剤、硬化促進 剤、酸化アンチモン、ハロゲン化エポキシ樹脂および無 機充填材を主成分とするが、これ以外にシランカップリ ング剤、カーボンブラック、ベンガラ等の着色剤、天然 ワックス、合成ワックス等の離型剤およびシリコーンオ イル、ゴム等の低応力添加剤等の種々の添加剤を適宜配 合して差し支えない。

【0011】還元剤として一般的に水素化合物、金属 塩、有機酸等が挙げられるが、水素化合物はそのほとん 【発明が解決しようとする課題】本発明は従来の高温条 40 どが液体でありその添加方法は難しく、また金属塩は信 頼性が低下するので好ましくない。有機酸は場合により 酸化剤にも還元剤にも作用するが、本発明に使用する還 元剤としては極めて酸化能力の低い有機酸が好ましい。 例えば、ギ酸、シュウ酸、アルコルビン酸等があり、特 に炭素数の少ないシュウ酸が好ましい。難燃剤として用 いるハロゲン化エポキシ樹脂と酸化アンチモンはその組 み合わせによって難燃化の相乗効果を大きく発揮させる ことが可能である。しかしながら、ハロゲン化エポキシ 樹脂は高温時においてハロゲンが遊離し易く腐食の原因 3

【0012】しかし、この問題は還元剤との組み合わせ で解決することが可能である。還元剤の添加量はエポキ シ樹脂、フェノールノボラック樹脂硬化剤、硬化促進 剤、酸化アンチモン、ハロゲン化エポキシ樹脂、無機充 填材およびその他の添加物からなる樹脂組成物100重 量部に対して0.01~10重量部の範囲が好ましい。 0.01重量部未満だと十分にその性能を発揮できな い。10重量部を越えると封止成形時の硬化性が悪化す る。還元剤の添加方法としては、あらかじめハロゲン化 エポキシ樹脂と少量のフェノールノボラック樹脂硬化剤 10 還元剤をアルコルビン酸にした他は実施例1と同一とし とを加熱溶融した後に、還元剤を添加し急速に冷却さ せ、この冷却物を粉砕し、残余の成分と混合するという 方法もある。

[0013]

【実施例】以下、本発明を実施例で具体的に説明する。 配合割合の部は重量部を表わす。

実施例1

溶融シリカ70部、エポキシ樹脂 (エポキシ当量20 0) 18部、フェノールノボラック樹脂硬化剤(水酸基 当量104)9部、DBU 0.5部、三酸化アンチモ ン3部、ハロゲン化エポキシ樹脂(エポキシ当量27 0)、カルナバワックス2部、カーボンブラック0.3 部、還元剤としてシュウ酸8部を常温で十分に混合し、

更に95~100℃でコニーダにより混練し、冷却後粉 砕して成形材料として、これをタブレット化して半導体 封止用樹脂組成物を得た。得られた材料を金型温度17 5℃、硬化時間2分の条件で成形硬化させ、得られた成 形品を175℃、8時間で後硬化した。この成形品を2 00℃の高温槽に放置し、50時間毎に取り出し、成形 品のリードピン間の抵抗を調べた。評価結果を表1に示

【0014】実施例2

た。評価結果を表1に示す。

【0015】比較例1~3

表1に示す配合割合で、実施例1と同様の方法で半導体 封止用樹脂組成物を得た。その評価結果を表1に示す。 【0016】評価方法

*高温抵抗変動率

成形品 (チップサイズ36m²、パッケージ厚2.0m m、ワイヤーボンディング有)の各リード間に電圧をか けた場合の抵抗値の変動率。初期抵抗値0.7 Ωに対し、 20 1Ω未満の時間をOとする。

[0017]

【表1】

6

表 1

		実 施 例		比較例			
		1	2	1	2	3	
エポキシ樹脂 フェノールノボラック樹脂 DBU 三酸化アンチモン ハロゲン化エポキシ樹脂 溶融シリカ カルナバワックス カーボンブラック		18 9 0.5 3 2 70 2 1.3					
還元	シュウ酸	8			0.005	15	
剤	アルコルビン酸		8	_			
硬化性		0	0	0	0	成形不可	
	50時間(200℃)	0	0	0	0		
高	100	0	0	0	0		
温	150	O.	0	0	0		
抵	200	0	0	0	0	-	
抗	250	0	0				
変	300	0	0				
動	350	0	0				
率	400	0	0				
	450						

【0018】 【発明の効果】本発明によると、耐燃性および成形性に 優れた半導体封止用樹脂組成物が得られるばかりでな *

*く、高温保管特性に優れた極めてバランスのとれた樹脂 組成物であり、工業的にも非常に信頼性の高いものであ る。

フロントページの続き

(51) Int. Cl.⁵

識別記号 庁内整理番号

FΙ

技術表示箇所

CO8L 61/10

LNB

8215-4J

63/00

NJS

8416-4J